74AUP2G14

Low-power dual Schmitt trigger inverter Rev. 5 — 4 December 2012

Product data sheet

General description 1.

The 74AUP2G14 provides two inverting buffers with Schmitt trigger action which accept standard input signals. They are capable of transforming slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H.

Features and benefits 2.

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5000 V
 - MM JESD22-A115-A exceeds 200 V
 - ◆ CDM JESD22-C101E exceeds 1000 V
- Low static power consumption; $I_{CC} = 0.9 \mu A$ (maximum)
- Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications

- Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator



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4. Ordering information

Table 1. Ordering information

| Type number | Package | | | | | | | | |
|-------------|-------------------|-------|-----------------------------------------------------------------------------------------------------------|---------|--|--|--|--|--|
| | Temperature range | Name | Description | Version | | | | | |
| 74AUP2G14GW | -40 °C to +125 °C | SC-88 | plastic surface-mounted package; 6 leads | SOT363 | | | | | |
| 74AUP2G14GM | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm | SOT886 | | | | | |
| 74AUP2G14GF | –40 °C to +125 °C | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1 \times 0.5 mm | SOT891 | | | | | |
| 74AUP2G14GN | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body $0.9 \times 1.0 \times 0.35$ mm | SOT1115 | | | | | |
| 74AUP2G14GS | –40 °C to +125 °C | XSON6 | extremely thin small outline package; no leads; 6 terminals; body 1.0 \times 1.0 \times 0.35 mm | SOT1202 | | | | | |

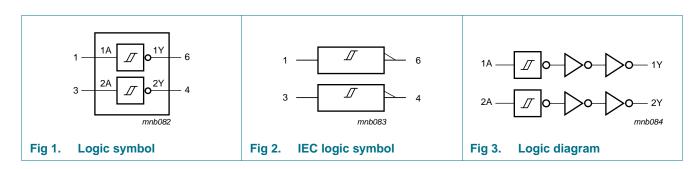
5. Marking

Table 2. Marking

| Type number | Marking code ^[1] |
|-------------|-----------------------------|
| 74AUP2G14GW | pK |
| 74AUP2G14GM | рК |
| 74AUP2G14GF | рК |
| 74AUP2G14GN | рК |
| 74AUP2G14GS | рК |

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

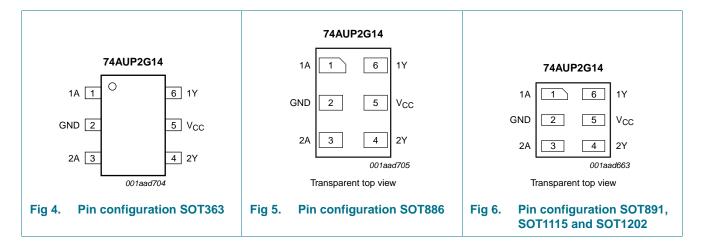
6. Functional diagram



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7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

| Symbol | Pin | Description |
|-----------------|-----|----------------|
| 1A | 1 | data input |
| GND | 2 | ground (0 V) |
| 2A | 3 | data input |
| 2Y | 4 | data output |
| V _{CC} | 5 | supply voltage |
| 1Y | 6 | data output |

8. Functional description

Table 4. Function table[1]

| Input | Output |
|-------|--------|
| nA | nY |
| L | Н |
| H | L |

^[1] H = HIGH voltage level; L = LOW voltage level.

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|-------------------------|----------------------------------------------------------------------|-------------------|------|------|
| V_{CC} | supply voltage | | -0.5 | +4.6 | V |
| I _{IK} | input clamping current | V _I < 0 V | -50 | - | mA |
| VI | input voltage | | [<u>1</u>] -0.5 | +4.6 | V |
| I _{OK} | output clamping current | V _O < 0 V | -50 | - | mA |
| Vo | output voltage | Active mode and Power-down mode | [<u>1</u>] -0.5 | +4.6 | V |
| Io | output current | $V_O = 0 V \text{ to } V_{CC}$ | - | ±20 | mA |
| I _{CC} | supply current | | - | 50 | mA |
| I_{GND} | ground current | | -50 | - | mA |
| T_{stg} | storage temperature | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$ | [2] _ | 250 | mW |

^[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|---------------------|-----------------------------------------|-----|----------|------|
| V_{CC} | supply voltage | | 0.8 | 3.6 | V |
| VI | input voltage | | 0 | 3.6 | V |
| Vo | output voltage | Active mode | 0 | V_{CC} | V |
| | | Power-down mode; $V_{CC} = 0 \text{ V}$ | 0 | 3.6 | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |

11. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------|---------------------------|----------------------------------------------------------------------------|-----------------------|-----|--------------------------|----------------|
| $T_{amb} = 2$ | 5 °C | | | | | |
| V_{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V}$ to 3.6 V | V _{CC} - 0.1 | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.75 \times V_{CC}$ | - | - | V |
| | | $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 1.11 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.32 | - | - | V |
| | | $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 2.05 | - | - | V |
| | | $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.9 | - | - | V |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.72 | - | - | V |
| | | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.6 | - | - | V |
| 74AUP2G14 | | All information provided in this document is subject to legal disclaimers. | | | © NXP B.V. 2012. All riç | ghts reserved. |

^[2] For SC-88 packages: above 87.5 $^{\circ}$ C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 packages: above 118 $^{\circ}$ C the value of P_{tot} derates linearly with 7.8 mW/K.

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Table 7. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Uni |
|----------------------|--------------------------------------|----------------------------------------------------------------------------------------------------|----------------------------------------------------|-----|---------------------|-----|
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | I_O = 20 μ A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.1 | V |
| | | $I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | - | - | $0.3 \times V_{CC}$ | V |
| | | $I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | - | - | 0.31 | V |
| | | $I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | - | - | 0.31 | V |
| | | $I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.31 | V |
| | | $I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.44 | V |
| | | $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.31 | V |
| | | $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.44 | V |
| l _l | input leakage current | $V_{I} = GND \text{ to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ | - | - | ±0.1 | μΑ |
| OFF | power-off leakage current | V_I or $V_O = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.2 | μΑ |
| Δl _{OFF} | additional power-off leakage current | $V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$ | - | - | ±0.2 | μΑ |
| Icc | supply current | V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V | $V_I = GND \text{ or } V_{CC}; I_O = 0 \text{ A};$ | | 0.5 | μΑ |
| Δl _{CC} | additional supply current | $V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A};$ - $V_{CC} = 3.3 \text{ V}$ | | - | 40 | μΑ |
| Cı | input capacitance | $V_I = GND \text{ or } V_{CC}$; $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$ | - | 1.1 | - | pF |
| Co | output capacitance | $V_O = GND; V_{CC} = 0 V$ | - | 1.7 | - | рF |
| T _{amb} = - | 40 °C to +85 °C | | | | | |
| V _{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_{O} = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | V _{CC} - 0.1 | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.7 \times V_{CC}$ | - | - | ٧ |
| | | $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 1.03 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.30 | - | - | ٧ |
| | | $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.97 | - | - | ٧ |
| | | $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.85 | - | - | ٧ |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.67 | - | - | V |
| | | $I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.55 | - | - | ٧ |
| V _{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.1 | V |
| | | I _O = 1.1 mA; V _{CC} = 1.1 V | - | - | $0.3 \times V_{CC}$ | V |
| | | $I_O = 1.7 \text{ mA}$; $V_{CC} = 1.4 \text{ V}$ | - | - | 0.37 | ٧ |
| | | I _O = 1.9 mA; V _{CC} = 1.65 V | - | - | 0.35 | V |
| | | I _O = 2.3 mA; V _{CC} = 2.3 V | - | - | 0.33 | V |
| | | I _O = 3.1 mA; V _{CC} = 2.3 V | - | - | 0.45 | V |
| | | $I_O = 2.7 \text{ mA}$; $V_{CC} = 3.0 \text{ V}$ | - | - | 0.33 | V |
| | | $I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.45 | V |
| <u> </u> | input leakage current | V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V | - | - | ±0.5 | μΑ |
| OFF | power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V | - | - | ±0.5 | μА |
| | | | | | | |

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 Table 7.
 Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--------------------------------------|--------------------------------------------------------------------------------|------------------------|-----|----------------------|------|
| ΔI_{OFF} | additional power-off leakage current | V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ±0.6 | μΑ |
| I _{CC} | supply current | V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 0.9 | μΑ |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$ | - | - | 50 | μΑ |
| T _{amb} = - | 40 °C to +125 °C | | | | | |
| V_{OH} | HIGH-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_{O} = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | V _{CC} – 0.11 | - | - | V |
| | | $I_{O} = -1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | $0.6 \times V_{CC}$ | - | - | V |
| | | $I_{O} = -1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | 0.93 | - | - | V |
| | | $I_{O} = -1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | 1.17 | - | - | V |
| | | $I_{O} = -2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.77 | - | - | V |
| | | $I_{O} = -3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | 1.67 | - | - | V |
| | | $I_{O} = -2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.40 | - | - | V |
| | | $I_{O} = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | 2.30 | - | - | V |
| V_{OL} | LOW-level output voltage | $V_I = V_{T+}$ or V_{T-} | | | | |
| | | $I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$ | - | - | 0.11 | V |
| | | $I_{O} = 1.1 \text{ mA}; V_{CC} = 1.1 \text{ V}$ | - | - | $0.33 \times V_{CC}$ | V |
| | | $I_{O} = 1.7 \text{ mA}; V_{CC} = 1.4 \text{ V}$ | - | - | 0.41 | V |
| | | $I_{O} = 1.9 \text{ mA}; V_{CC} = 1.65 \text{ V}$ | - | - | 0.39 | V |
| | | $I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.36 | V |
| | | $I_{O} = 3.1 \text{ mA}; V_{CC} = 2.3 \text{ V}$ | - | - | 0.50 | V |
| | | $I_{O} = 2.7 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.36 | V |
| | | $I_{O} = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$ | - | - | 0.50 | V |
| I _I | input leakage current | $V_I = GND$ to 3.6 V; $V_{CC} = 0$ V to 3.6 | 5 V - | - | ±0.75 | μΑ |
| I_{OFF} | power-off leakage current | V_I or V_O = 0 V to 3.6 V; V_{CC} = 0 V | - | - | ±0.75 | μΑ |
| ΔI_{OFF} | additional power-off leakage current | V_{I} or $V_{O} = 0$ V to 3.6 V; $V_{CC} = 0$ V to 0.2 V | - | - | ±0.75 | μΑ |
| I _{CC} | supply current | V_I = GND or V_{CC} ; I_O = 0 A; V_{CC} = 0.8 V to 3.6 V | - | - | 1.4 | μΑ |
| ΔI_{CC} | additional supply current | $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 3.3 \text{ V}$ | - | - | 75 | μΑ |

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12. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

| Symbol | Parameter | Conditions | | 25 °C | | -40 °C to +125 °C | | | Unit |
|-----------------------|-------------------|----------------------------------------------|-----|--------|------|-------------------|----------------|-----------------|------|
| | | | | Typ[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| C _L = 5 pl | F | | ' | | | | | | ' |
| t _{pd} | propagation delay | nA to nY; see Figure 7 | | | | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | - | 19.9 | - | - | - | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | 2.7 | 5.9 | 11.0 | 2.4 | 11.1 | 11.2 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | 2.6 | 4.3 | 6.6 | 2.4 | 7.1 | 7.4 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 2.1 | 3.7 | 5.4 | 2.0 | 6.0 | 6.2 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 2.0 | 3.0 | 4.1 | 1.7 | 4.5 | 4.7 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 1.9 | 2.8 | 3.6 | 1.5 | 3.9 | 4.0 | ns |
| C _L = 10 | ρF | | | | | | | | |
| t _{pd} | propagation delay | nA to nY; see Figure 7 | | | | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | - | 23.4 | - | - | - | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | 2.9 | 6.8 | 12.7 | 2.8 | 12.8 | 12.9 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | 2.8 | 5.0 | 7.7 | 2.6 | 8.2 | 8.6 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 2.7 | 4.2 | 6.2 | 2.5 | 6.7 | 7.1 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 2.3 | 3.6 | 4.8 | 2.1 | 5.2 | 5.5 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 2.1 | 3.3 | 4.3 | 2.0 | 4.5 | 4.7 | ns |
| C _L = 15 | ρF | | | | | | | | |
| t_{pd} | propagation delay | nA to nY; see Figure 7 | | | | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | - | 26.9 | - | - | - | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | 3.3 | 7.6 | 14.3 | 3.0 | 14.5 | 14.7 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | 3.3 | 5.5 | 8.6 | 2.9 | 9.4 | 9.8 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 2.8 | 4.7 | 7.0 | 2.8 | 7.7 | 8.1 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | 2.7 | 4.0 | 5.5 | 2.4 | 5.9 | 6.2 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 2.6 | 3.8 | 4.8 | 2.2 | 5.2 | 5.4 | ns |
| $C_L = 30$ | oF | | | | | | | | |
| t_{pd} | propagation delay | nA to nY; see Figure 7 | | | | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | - | 37.3 | - | - | - | - | ns |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | 4.0 | 9.8 | 18.7 | 3.9 | 19.6 | 20.0 | ns |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | 3.7 | 7.1 | 11.2 | 3.8 | 12.3 | 12.9 | ns |
| | | $V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$ | 3.6 | 6.0 | 9.1 | 3.6 | 10.0 | 10.6 | ns |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | 3.5 | 5.2 | 6.9 | 3.2 | 7.5 | 7.9 | ns |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | 3.3 | 4.8 | 6.1 | 3.1 | 7.1 | 7.4 | ns |

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 Table 8.
 Dynamic characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

| Symbol | Parameter | Conditions | | 25 °C | | –40 °C to +125 °C | | | Unit | |
|--------------|-------------------------------|----------------------------------------------------|--------|-------|--------|-------------------|-----|----------------|-----------------|----|
| | | | - | Min | Typ[1] | Max | Min | Max (85 °C) | Max (125 °C) | |
| $C_L = 5 pl$ | F, 10 pF, 15 pF and | 30 pF | | | | | | | | |
| C_{PD} | power dissipation capacitance | $f_i = 1 \text{ MHz}; V_I = \text{GND to } V_{CC}$ | [3][4] | | | | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | | - | 2.6 | - | - | - | - | pF |
| | | $V_{CC} = 1.1 \text{ V to } 1.3 \text{ V}$ | | - | 2.7 | - | - | - | - | pF |
| | | $V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$ | | - | 2.9 | - | - | - | - | pF |
| | | V_{CC} = 1.65 V to 1.95 V | | - | 3.1 | - | - | - | - | pF |
| | | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$ | | - | 3.7 | - | - | - | - | pF |
| | | $V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$ | | - | 4.3 | - | - | - | - | pF |

- [1] All typical values are measured at nominal V_{CC}.
- [2] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [3] All specified values are the average typical values over all stated loads.
- [4] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz;

 $f_o = output frequency in MHz;$

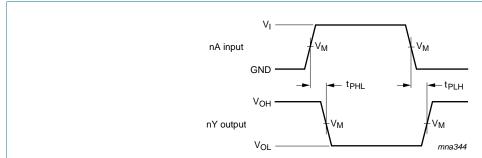
C_L = load capacitance in pF;

 V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

13. Waveforms



Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

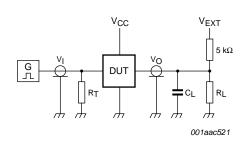
Fig 7. The data input (nA) to output (nY) propagation delays

Table 9. Measurement points

| Supply voltage | Output | Input | | | | | | |
|-----------------|---------------------|---------------------|-----------------|-------------|--|--|--|--|
| V _{CC} | V _M | V _M | V _I | $t_r = t_f$ | | | | |
| 0.8 V to 3.6 V | $0.5 \times V_{CC}$ | $0.5 \times V_{CC}$ | V _{CC} | ≤ 3.0 ns | | | | |

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Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

Table 10. Test data

| Supply voltage | Load | | V _{EXT} | | |
|-----------------|------------------------------|------------------------------|-------------------------------------|-------------------------------------|-------------------------------------|
| V _{CC} | CL | R _L [1] | t _{PLH} , t _{PHL} | t _{PZH} , t _{PHZ} | t _{PZL} , t _{PLZ} |
| 0.8 V to 3.6 V | 5 pF, 10 pF, 15 pF and 30 pF | 5 k Ω or 1 M Ω | open | GND | $2 \times V_{CC}$ |

^[1] For measuring enable and disable times $R_L = 5 \text{ k}\Omega$, for measuring propagation delays, set-up and hold times and pulse width $R_L = 1 \text{ M}\Omega$.

14. Transfer characteristics

Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 8.

| Symbol I | Parameter | Conditions | | 25 °C | | -40 °C to +125 °C | | | Unit |
|--------------------------------|-------------------------------------|----------------------------|------|-------|------|-------------------|----------------|-----------------|------|
| | | | Min | Тур | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _{T+} positive-going | see Figure 9 and Figure 10 | | | | | | | | |
| | threshold voltage | $V_{CC} = 0.8 \text{ V}$ | 0.30 | - | 0.60 | 0.30 | 0.60 | 0.62 | V |
| | | V _{CC} = 1.1 V | 0.53 | - | 0.90 | 0.53 | 0.90 | 0.92 | V |
| | | V _{CC} = 1.4 V | 0.74 | - | 1.11 | 0.74 | 1.11 | 1.13 | V |
| | | V _{CC} = 1.65 V | 0.91 | - | 1.29 | 0.91 | 1.29 | 1.31 | V |
| | | $V_{CC} = 2.3 \text{ V}$ | 1.37 | - | 1.77 | 1.37 | 1.77 | 1.80 | V |
| | $V_{CC} = 3.0 \text{ V}$ | 1.88 | - | 2.29 | 1.88 | 2.29 | 2.32 | V | |
| | negative-going threshold voltage | see Figure 9 and Figure 10 | | | | | | | |
| | | $V_{CC} = 0.8 \text{ V}$ | 0.10 | - | 0.60 | 0.10 | 0.60 | 0.60 | V |
| | | V _{CC} = 1.1 V | 0.26 | - | 0.65 | 0.26 | 0.65 | 0.65 | V |
| | | V _{CC} = 1.4 V | 0.39 | - | 0.75 | 0.39 | 0.75 | 0.75 | V |
| | | V _{CC} = 1.65 V | 0.47 | - | 0.84 | 0.47 | 0.84 | 0.84 | V |
| | | $V_{CC} = 2.3 \text{ V}$ | 0.69 | - | 1.04 | 0.69 | 1.04 | 1.04 | V |
| | | $V_{CC} = 3.0 \text{ V}$ | 0.88 | - | 1.24 | 0.88 | 1.24 | 1.24 | V |

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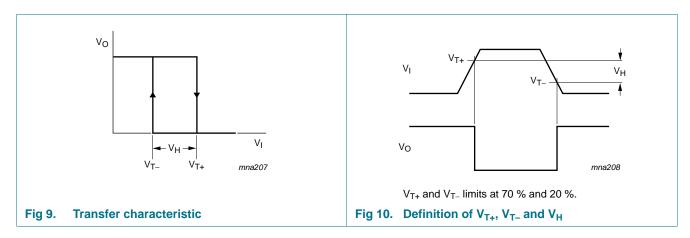
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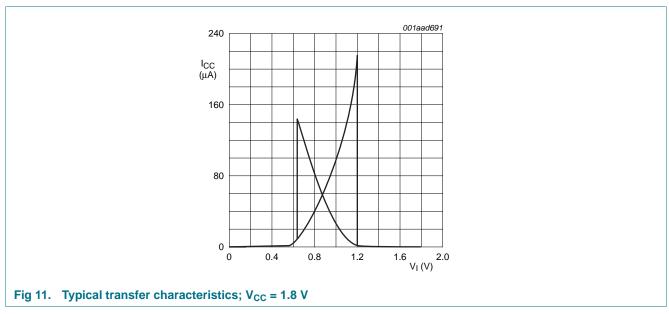
Table 11. Transfer characteristics ...continued

Voltages are referenced to GND (ground = 0 V); for test circuit see <u>Figure 8</u>.

| Symbol | Parameter | Conditions | 25 °C | | -40 °C to +125 °C | | | Unit | |
|-----------------------------------|----------------------------------------------------------------------------------------------------------------------------|--------------------------|-------|-----|-------------------|------|----------------|-----------------|---|
| | | | Min | Тур | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _H hysteresis voltage | (V _{T+} – V _{T-}); see <u>Figure 9</u> , <u>Figure 10</u> , <u>Figure 11</u> and <u>Figure 12</u> | | | | | | | | |
| | | V _{CC} = 0.8 V | 0.07 | - | 0.50 | 0.07 | 0.50 | 0.50 | V |
| | | V _{CC} = 1.1 V | 0.08 | - | 0.46 | 0.08 | 0.46 | 0.46 | V |
| | | V _{CC} = 1.4 V | 0.18 | - | 0.56 | 0.18 | 0.56 | 0.56 | V |
| | | V _{CC} = 1.65 V | 0.27 | - | 0.66 | 0.27 | 0.66 | 0.66 | V |
| | | V _{CC} = 2.3 V | 0.53 | - | 0.92 | 0.53 | 0.92 | 0.92 | V |
| | | V _{CC} = 3.0 V | 0.79 | - | 1.31 | 0.79 | 1.31 | 1.31 | V |

15. Waveforms transfer characteristics





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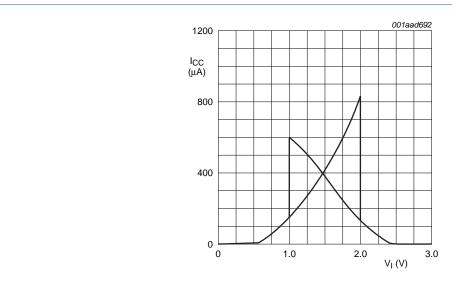


Fig 12. Typical transfer characteristics; $V_{CC} = 3.0 \text{ V}$

16. Application information

The slow input rise and fall times cause additional power dissipation, this can be calculated using the following formula:

 $P_{add} = f_i \times (t_r \times \Delta I_{CC(AV)} + t_f \times \Delta I_{CC(AV)}) \times V_{CC}$ where:

 P_{add} = additional power dissipation (μW);

 $f_i = input frequency (MHz);$

 t_r = rise time (ns); 10 % to 90 %;

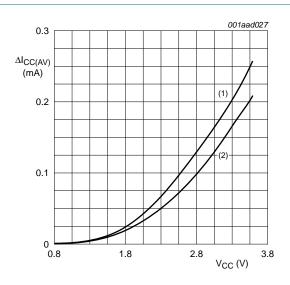
 $t_f = \text{fall time (ns)}; 90 \% \text{ to } 10 \%;$

 $\Delta I_{CC(AV)}$ = average additional supply current (μA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 13.

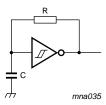
An example of a relaxation circuit using the 74AUP2G14 is shown in Figure 14.

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- (1) Positive-going edge.
- (2) Negative-going edge.

Fig 13. Average I_{CC} as a function of V_{CC}



$$f = \frac{1}{T} \approx \frac{1}{a \times RC}$$

Average values for variable a are given in Table 12.

Fig 14. Relaxation oscillator

Table 12. Variable values

| Supply voltage | Variable a |
|----------------|------------|
| 1.1 V | 1.28 |
| 1.5 V | 1.22 |
| 1.8 V 2.8 V | 1.24 |
| | 1.34 |
| 3.3 V | 1.45 |

17. Package outline

Plastic surface-mounted package; 6 leads

SOT363

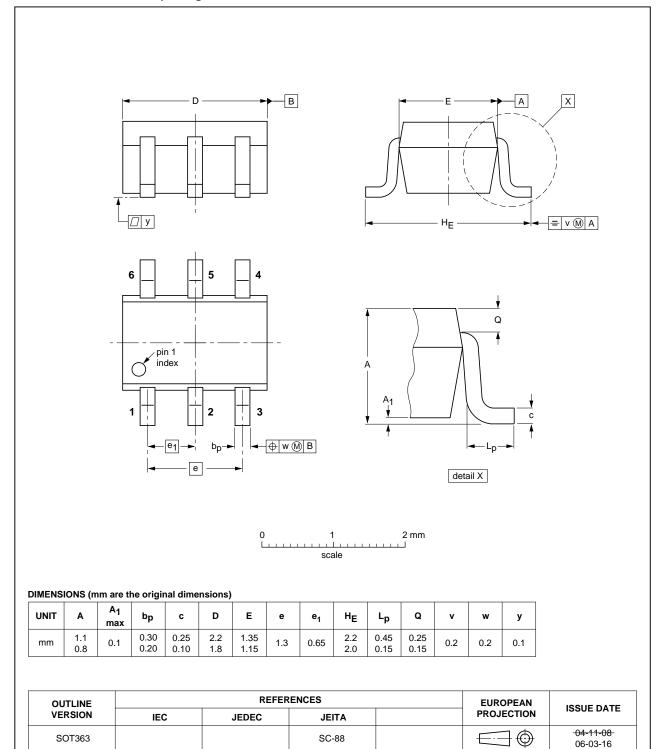


Fig 15. Package outline SOT363 (SC-88)

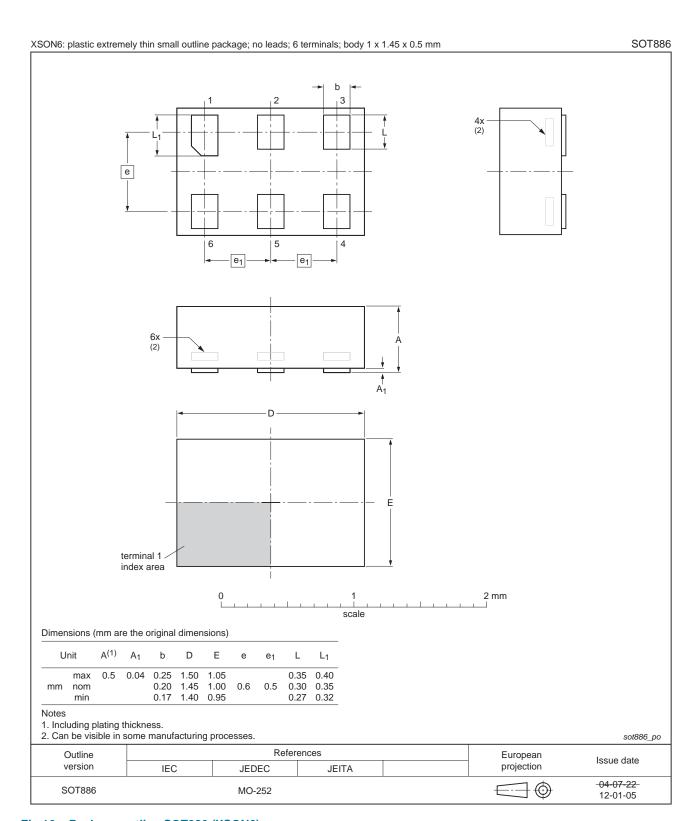


Fig 16. Package outline SOT886 (XSON6)

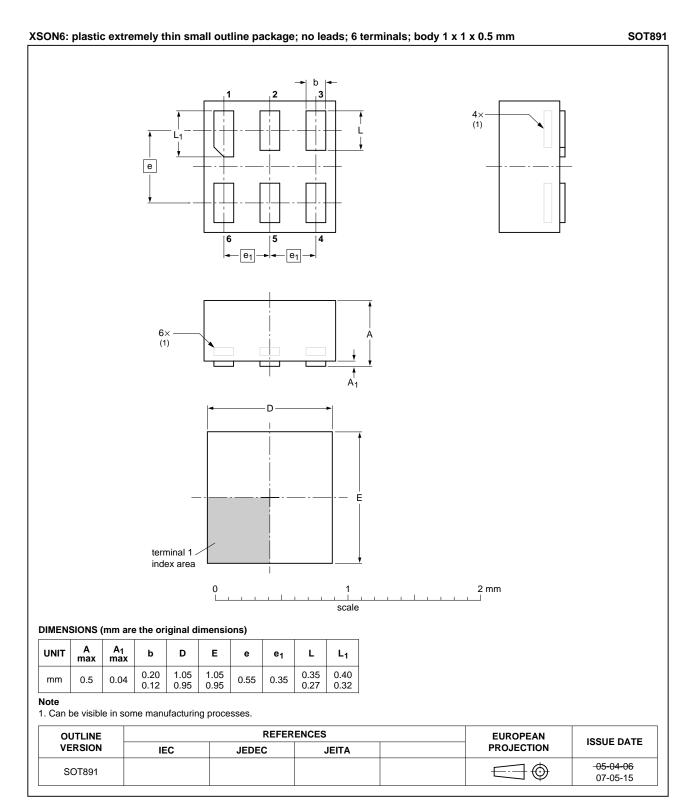


Fig 17. Package outline SOT891 (XSON6)

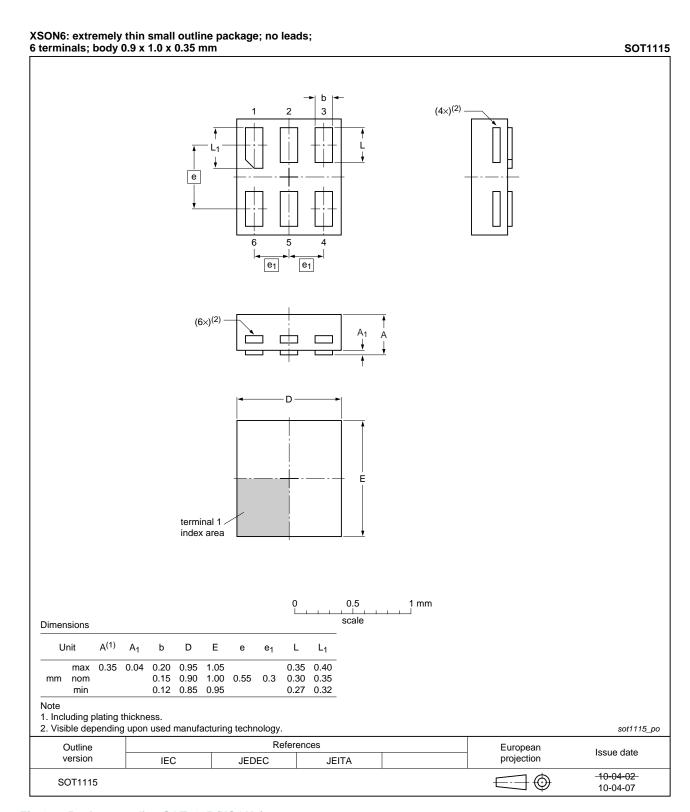


Fig 18. Package outline SOT1115 (XSON6)

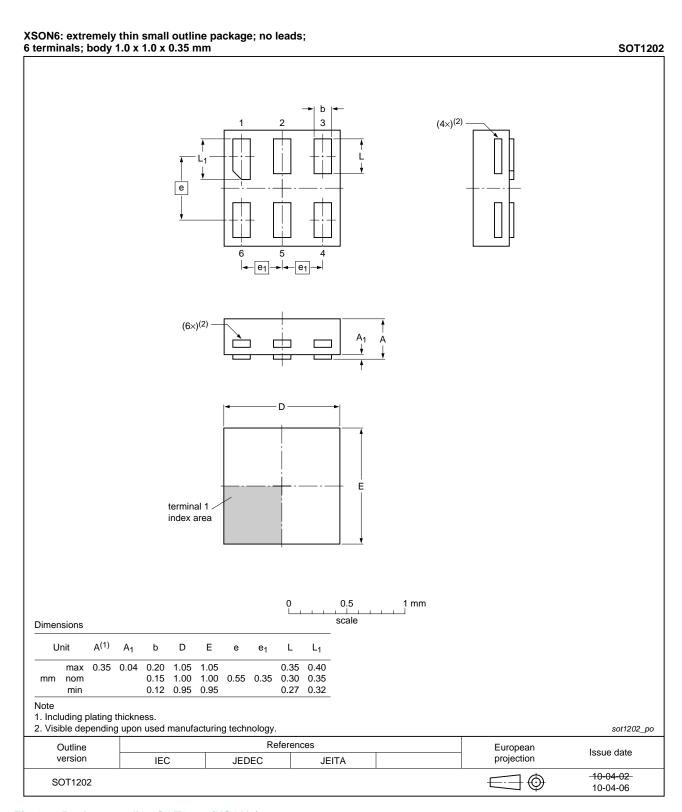


Fig 19. Package outline SOT1202 (XSON6)

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18. Abbreviations

Table 13. Abbreviations

| Acronym | Description |
|---------|-------------------------|
| CDM | Charged Device Model |
| DUT | Device Under Test |
| ESD | ElectroStatic Discharge |
| НВМ | Human Body Model |
| MM | Machine Model |

19. Revision history

Table 14. Revision history

| | • | | | |
|----------------|--------------------------------|----------------------------|---------------------|---------------|
| Document ID | Release date | Data sheet status | Change notice | Supersedes |
| 74AUP2G14 v.5 | 20121204 | Product data sheet | - | 74AUP2G14 v.4 |
| Modifications: | Package ou | tline drawing of SOT886 (F | igure 16) modified. | |
| 74AUP2G14 v.4 | 20111201 | Product data sheet | - | 74AUP2G14 v.3 |
| 74AUP2G14 v.3 | 20100722 | Product data sheet | - | 74AUP2G14 v.2 |
| 74AUP2G14 v.2 | 20090703 | Product data sheet | - | 74AUP2G14 v.1 |
| 74AUP2G14 v.1 | 20061219 | Product data sheet | - | - |
| | | | | |

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